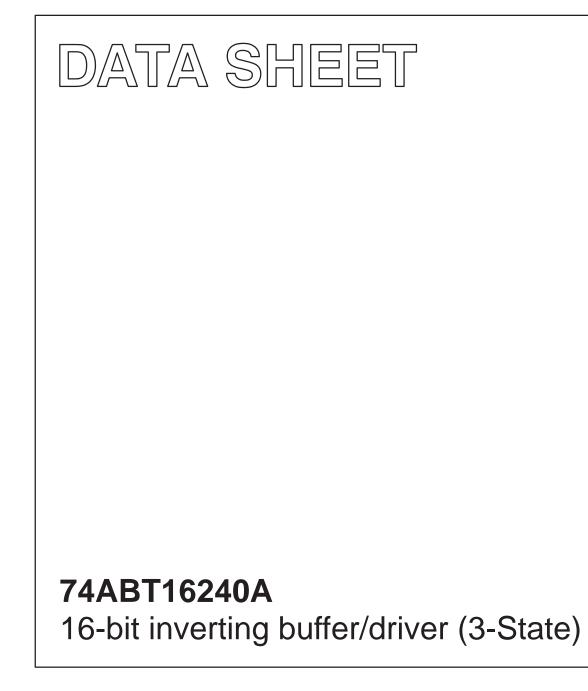
INTEGRATED CIRCUITS



Product data Replaces data sheet 74ABT/H16240A of 1998 Feb 25 2004 Feb 12



Philips Semiconductors

74ABT16240A

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Live insertion/extraction permitted
- Power-up 3-State
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

QUICK REFERENCE DATA

DESCRIPTION

The 74ABT16240A is a high-performance BiCMOS device which combines low static and dynamic power dissipation with high speed and high output drive.

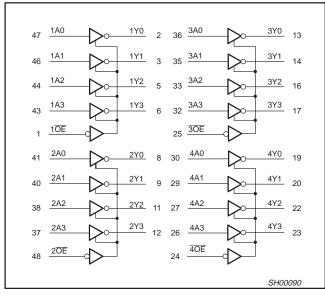
This device is an inverting 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables $(1\overline{OE}, 2\overline{OE}, 3\overline{OE}, 4\overline{OE})$, each controlling four of the 3-State outputs.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50 pF;$ $V_{CC} = 5V$	2.0 1.5	ns
C _{IN}	Input capacitance nOE	$V_{I} = 0V \text{ or } 3.0V$	4	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_0 = 0V$ or	6	pF
I _{CCZ}	Quiescent supply current	Outputs disabled; V _{CC} =	500	μΑ
I _{CCL}		Outputs low; $V_{CC} = 5.5V$	9	mA

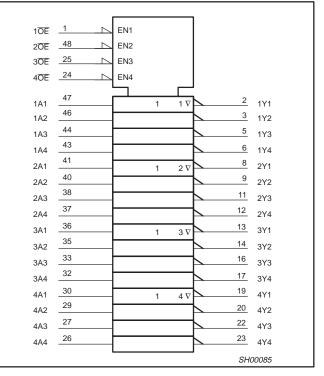
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ABT16240A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT16240A DGG	SOT362-1

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



16-bit inverting buffer/driver (3-State)

PIN CONFIGURATION

		1
1 0E	1	48 20E
1Y0	2	47 1A0
1Y1	3	46 1A1
GND	4	45 GND
1Y2	5	44 1A2
1Y3	6	43 1A3
V _{CC}	7	42 VCC
2Y0	8	41 2A0
2Y1	9	40 2A1
GND	10	39 GND
2Y2	11	38 2A2
2Y3	12	37 2A3
3Y0	13	36 3A0
3Y1	14	35 3A1
GND	15	34 GND
3Y2	16	33 3A2
3Y4	17	32 3A3
V _{CC}	18	31 V _{CC}
4Y0	19	30 4A0
4Y1	20	29 4A1
GND	21	28 GND
4Y2	22	27 4A2
4Y3	23	26 4A3
40E	24	25 3OE
	L	J 6400012
		SA00013

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION				
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1A0-1A3 2A0-2A3 3A0-3A3 4A0-4A3	Data inputs				
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1 <u>7</u> 0-1 <u>7</u> 3 2 <u>7</u> 0-2 <u>7</u> 3 3 <u>7</u> 0-3 <u>7</u> 3 4 <u>7</u> 0-4 <u>7</u> 3	Data outputs				
1, 48, 25, 24	1 <u>0E,</u> 2 <u>0E,</u> 30E, 40E	Output enables				
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)				
7, 18, 31, 42	V _{CC}	Positive supply voltage				

FUNCTION TABLE

Inp	uts	Outputs
n <mark>OE</mark>	nAx	nYx
L	L	Н
L	Н	L
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{OK}	DC output diode current	utput diode current V _O < 0		mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +5.5	V
		Output in Low state	128	
OUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

16-bit inverting buffer/driver (3-State)

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT	
STMBOL	PARAMETER	MIN	MAX		
V _{CC}	DC supply voltage	4.5	5.5	V	
VI	Input voltage	0	V _{CC}	V	
VIH	High-level input voltage			V	
VIL	/IL Input voltage		0.8	V	
I _{OH}	High-level output current		-32	mA	
I _{OL}	Low-level output current		32	mA	
	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		64		
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled	0	10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

DC ELECTRICAL CHARACTERISTICS

					LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS					-40°C 85°C		
			Min	Тур	Max	Min	Max		
V _{IK}	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V	
		V_{CC} = 4.5V; I_{OH} = -3mA; V_I = V_{IL} or V_{IH}	2.5	2.9		2.5		V	
V _{OH}	High-level output voltage	V_{CC} = 5.0V; I_{OH} = -3mA; V_I = V_{IL} or V_{IH}	3.0	3.4		3.0		V	
		V_{CC} = 4.5V; I_{OH} = -32mA; V_I = V_{IL} or V_{IH}	2.0	2.4		2.0		V	
V _{OL}	Low-level output voltage	V_{CC} = 4.5V; I_{OL} = 64mA; V_I = V_{IL} or V_{IH}		0.42	0.55		0.55	V	
l _l	Input leakage current	V_{CC} = 5.5V; V_{I} = GND or 5.5V		±0.01	±1.0		±1.0	μΑ	
I _{OFF}	Power-off leakage current	V_{CC} = 0.0V; V_O or $V_I \leq 4.5V$		±5.0	±100		±100	μΑ	
I _{PU} /I _{PD}	Power-up/down 3-State output current	$V_{\underline{CC}} = 2.0V; V_{\underline{O}} = 0.5V; V_{\underline{I}} = GND \text{ or } V_{\underline{CC}}; V_{\underline{OE}} = V_{\underline{CC}}$		±5.0	±50		±50	μΑ	
I _{OZH}	3-State output High current	V_{CC} = 5.5V; V_{O} = 2.7V; V_{I} = V_{IL} or V_{IH}		1.0	10		10	μΑ	
I _{OZL}	3-State output Low current	V_{CC} = 5.5V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}		-1.0	-10		-10	μΑ	
I _{CEX}	Output high leakage current	V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND or V_{CC}		1.0	50		50	μΑ	
Ι _Ο	Output current ¹	$V_{CC} = 5.5V; V_{O} = 2.5V$	-50	-70	-180	-50	-180	mA	
I _{ССН}		V_{CC} = 5.5V; Outputs High, V_I = GND or V_{CC}		0.5	1.0		1.0	mA	
I _{CCL}	Quiescent supply current	V_{CC} = 5.5V; Outputs Low, V_I = GND or V_{CC}		8	19		19	mA	
Iccz		V_{CC} = 5.5V; Outputs 3-State; V _I = GND or V _{CC}		0.5	1.0		1.0	mA	
ΔI_{CC}	Additional supply current per input pin ²	Outputs enabled, one input at 3.4V, other inputs at V _{CC} or GND; $V_{CC} = 5.5V$		10	200		200	μΑ	

NOTES:

Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
 This is the increase in supply current for each input at 3.4V.

Product data

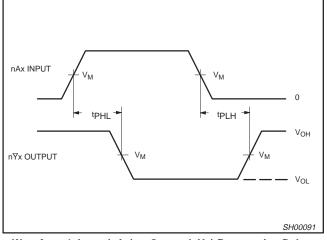
AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

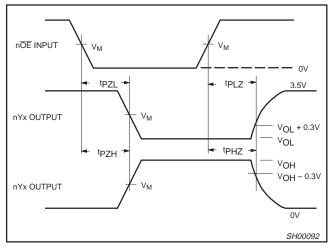
					LIMI	ſS		
SYMBOL	PARAMETER	WAVEFORM	$\begin{array}{c} T_{amb} = +25^{\circ}C & T_{amb} = -40^{\circ}C \ to \ +85^{\circ}C \\ V_{CC} = +5.0V & V_{CC} = +5.0V \ \pm 0.5V \end{array}$			°C to +85°C .0V ±0.5V	UNIT	
			Min	Тур	Мах	Min	Мах	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1.0 1.0	2.0 1.5	3.0 3.0	1.0 1.0	3.7 3.5	ns
t _{PZH} t _{PZL}	Output enable time 2 2		1.2 1.2	2.4 2.3	3.3 3.2	1.2 1.0	4.2 4.2	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.3 1.3	2.7 2.5	4.1 3.6	1.6 1.4	4.7 4.1	ns

AC WAVEFORMS

 $V_{\rm M} = 1.5$ V, $V_{\rm IN} =$ GND to 2.7V



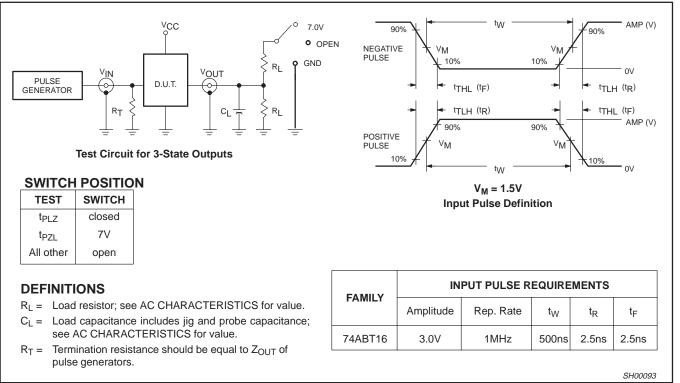
Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

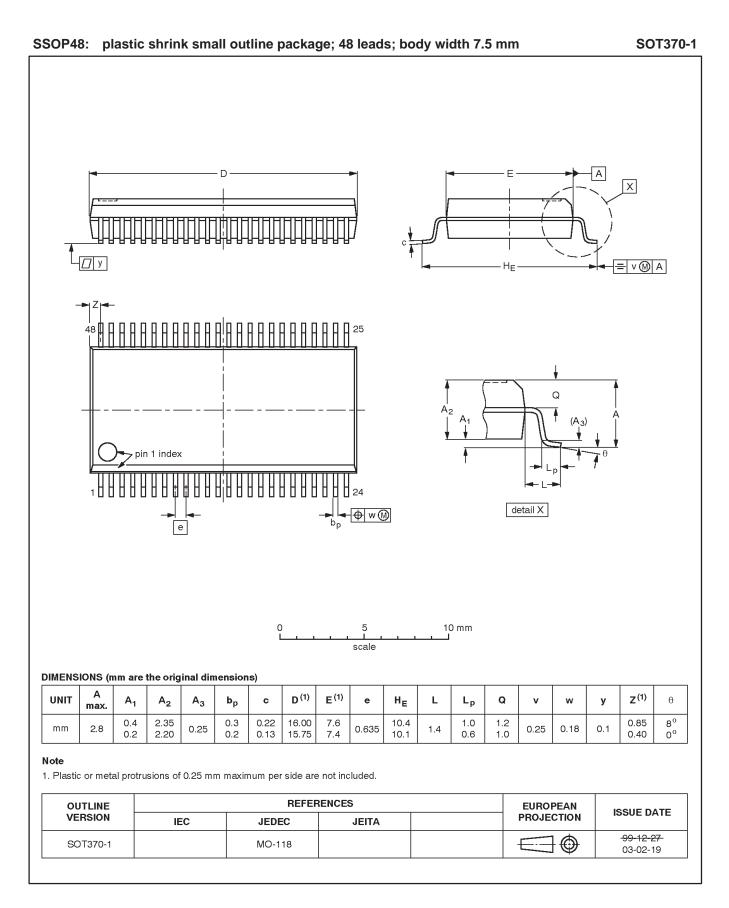
16-bit inverting buffer/driver (3-State)

TEST CIRCUIT AND WAVEFORMS

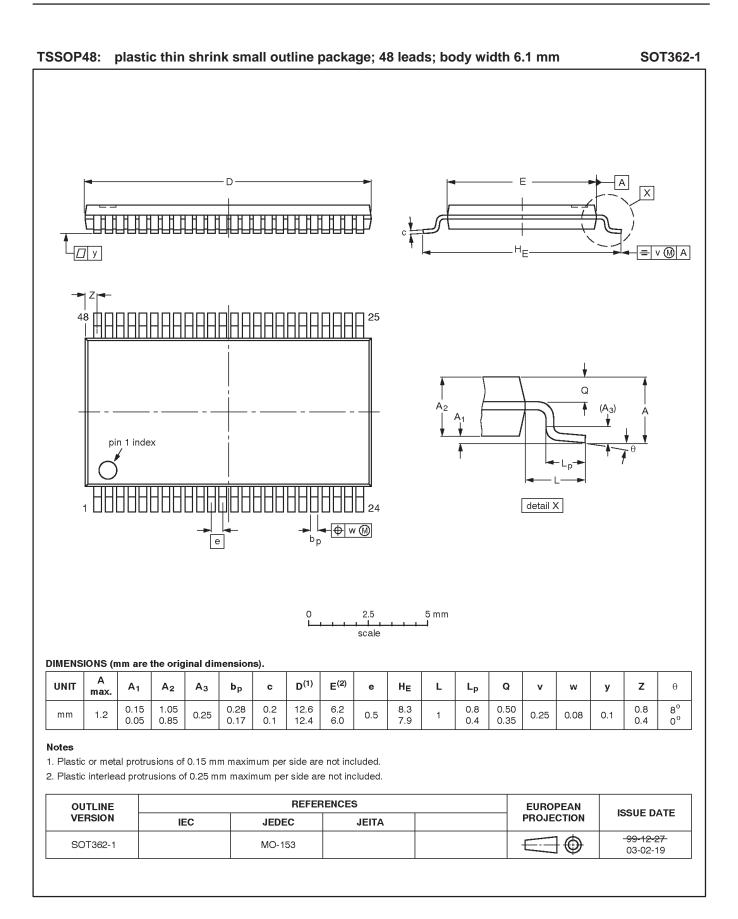


2004 Feb 12

74ABT16240A



74ABT16240A



74ABT16240A

REVISION HISTORY

Rev	Date	Description
_3	20040212	Product data (9397 750 12893); 853-1880 ECN 01–A15420 of 26 January 2004. Replaces data sheet 74ABT_H16240_2 of 1998 Feb 25 (9397 750 03481).
		Modifications:
		 Delete all references to 74ABTH16240 (product discontinued).
_2	19980225	Product data (9397 750 03481); ECN 853-1880 19019 of 25 February 1998. Supersedes initial version.

74ABT16240A

Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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